

Analog Devices Welcomes Hittite Microwave Corporation

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HMC430* Product Page Quick Links

Last Content Update: 08/30/2016

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- HMC430LP4 Evaluation Board

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Data Sheet

- HMC430 Data Sheet

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Quality Documentation

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

[Design Resources](#)

- HMC430 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

[Discussions](#)

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Typical Applications

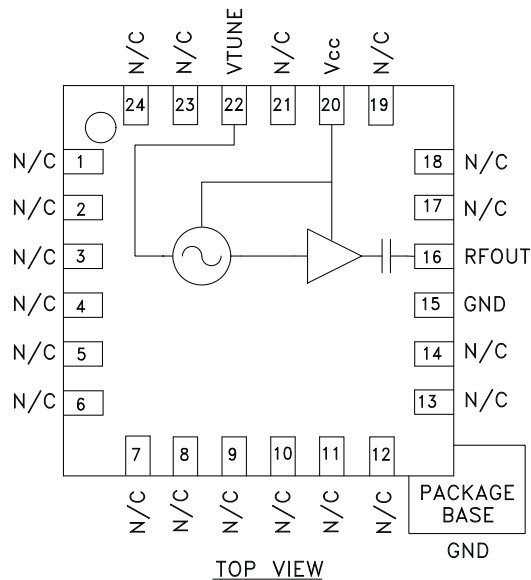
Low noise MMIC VCO w/Buffer Amplifier for C-Band applications such as:

- 802.11a & HiperLAN WLAN
- VSAT Radios
- UNII & Point-to-Point Radios

Features

- Pout: +2 dBm
- Phase Noise: -103 dBc/Hz @100 kHz
- No External Resonator Needed
- Single Supply: 3V @ 27 mA
- 16mm² Leadless SMT Package

Functional Diagram



General Description

The HMC430LP4 & HMC430LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. The VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 2 dBm typical from a 3V supply voltage. The voltage controlled oscillator is packaged in a low cost leadless QFN 4 x 4 mm surface mount package.

Electrical Specifications, $T_A = +25^\circ \text{C}$, $V_{cc} = +3\text{V}$

Parameter	Min.	Typ.	Max.	Units
Frequency Range	5.0 - 5.5			GHz
Power Output	-1	2		dBm
SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5\text{V}$ @ RF Output		-103		dBc/Hz
Tune Voltage (V_{tune})	0		10	V
Supply Current (I_{cc}) ($V_{cc} = +3.0\text{V}$)		27		mA
Tune Port Leakage Current			10	μA
Output Return Loss		6		dB
Harmonics 2nd 3rd		-15 -25		dBc dBc
Pulling (into a 2.0:1 VSWR)		12		MHz pp
Pushing @ $V_{tune} = +5\text{V}$		12		MHz/V
Frequency Drift Rate		0.8		MHz/ $^\circ\text{C}$

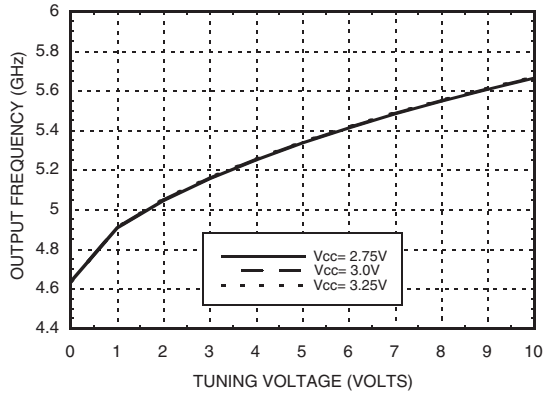
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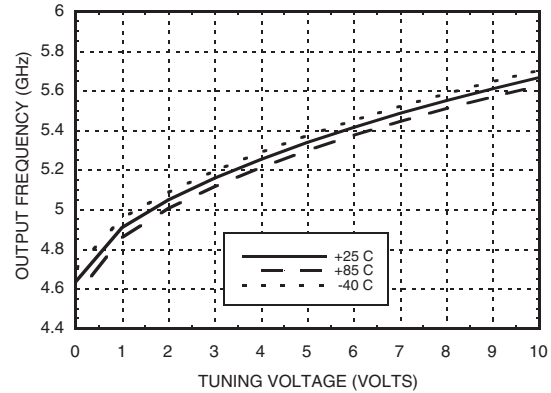
HMC430LP4 / 430LP4E

MMIC VCO w/ BUFFER AMPLIFIER, 5.0 - 5.5 GHz

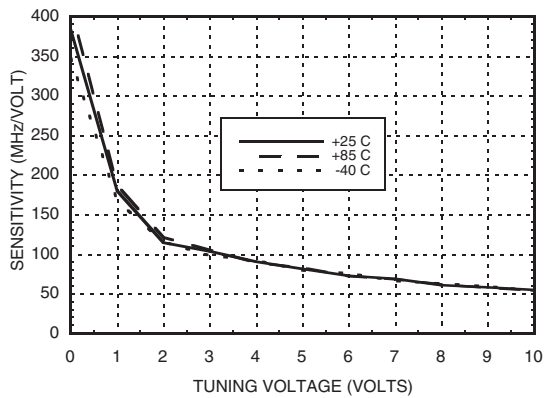
Frequency vs. Tuning Voltage, $T = 25^\circ\text{C}$



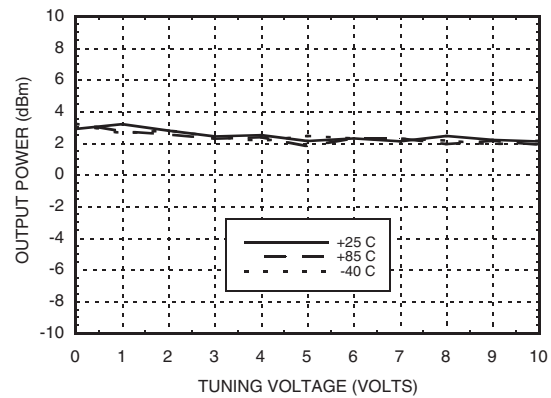
Frequency vs. Tuning Voltage, $V_{cc} = +3V$



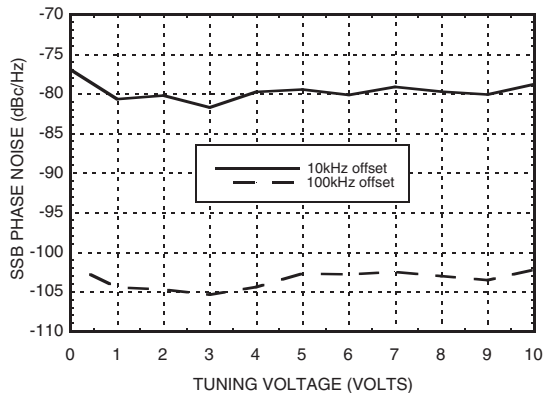
Sensitivity vs. Tuning Voltage, $V_{cc} = +3V$



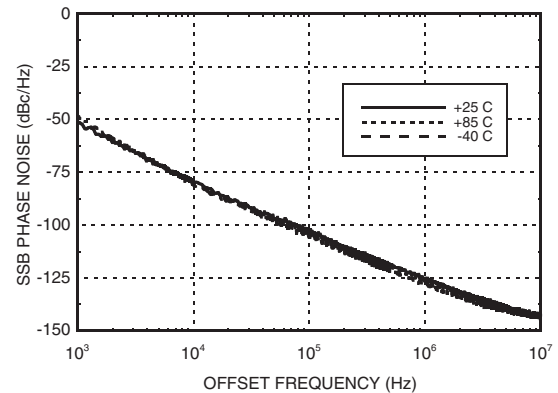
Output Power vs. Tuning Voltage, $V_{cc} = +3V$



Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ $V_{tune} = +5V$



Absolute Maximum Ratings

Vcc	+3.5 Vdc
Vtune	0 to +11V
Junction Temperature	135 °C
Continuous P _{diss} (T = 85°C) (derate 2.1 mW/°C above 85°C)	104 mW
Thermal Resistance (junction to ground paddle)	482 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Typical Supply Current vs. Vcc

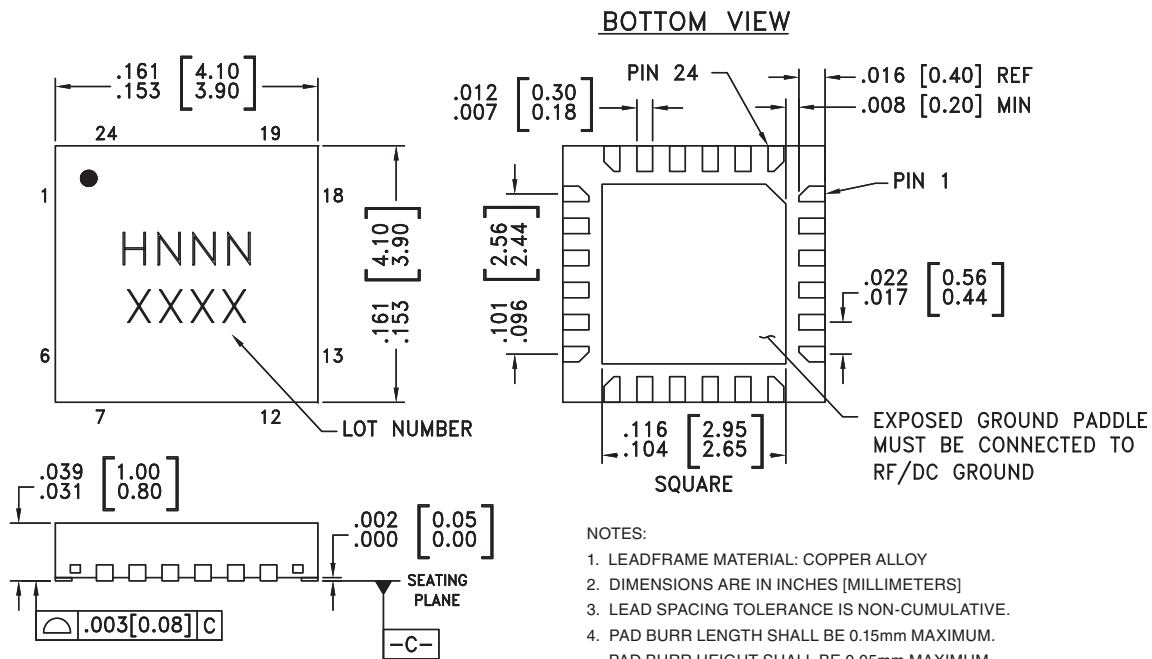
Vcc (V)	I _{cc} (mA)
2.75	19
3.0	27
3.25	34

Note: VCO will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC430LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H430 XXXX
HMC430LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H430 XXXX

[1] Max peak reflow temperature of 235 °C


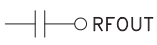
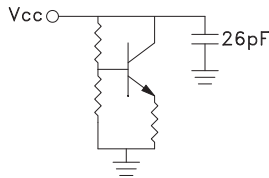
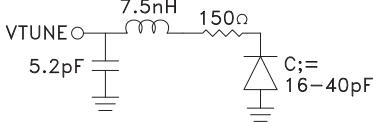

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

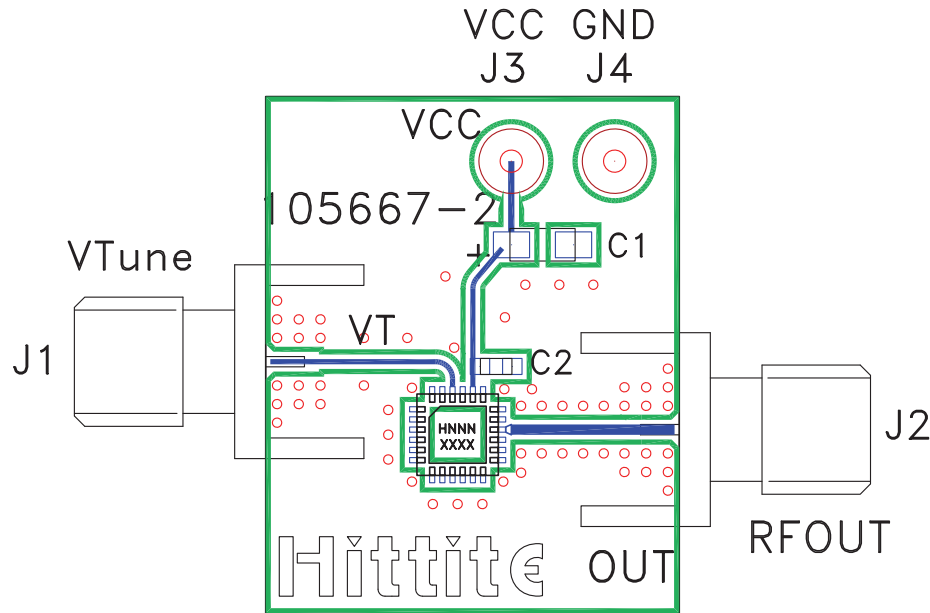
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground.	
16	RFOUT	RF output (AC coupled)	
20	Vcc	Supply Voltage Vcc= 3V	
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	

Evaluation PCB



List of Materials for Evaluation PCB 105706 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J4	DC Pin
C1	4.7 μ F Tantalum Capacitor
C2	10,000 pF Capacitor, 0603 Pkg.
U1	HMC430LP4 / HMC430LP4E VCO
PCB [2]	105667 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



HMC430LP4 / 430LP4E

**MMIC VCO w/ BUFFER
AMPLIFIER, 5.0 - 5.5 GHz**

Notes: